



N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)}	I _D T _A = +25°C
	0.6Ω @ V _{GS} = 4.5V	0.9A
20V	0.8Ω @ V _{GS} = 2.5V	0.7A
	1.0Ω @ V _{GS} = 1.8V	0.5A
	1.6Ω @ V _{GS} = 1.5V	0.3A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Power Management Functions
- Battery Operated Systems and Solid-State Relays
- Load Switch

Features and Benefits

- Low On-Resistance
- Very low Gate Threshold Voltage, 1.0V Max.
- Low Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

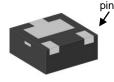
- Case: U-DFN1212-3
- Case Material: Molded Plastic;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe; Solderable per MIL-STD-202, Method 208 €4
- Terminal Connections: See Diagram
- Weight: 0.005 grams (Approximate)

U-DFN1212-3

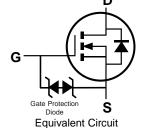


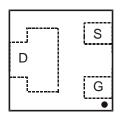


Top View



Bottom View





Pin-out Top view

Ordering Information (Note 5)

Part Number	Case	Packaging
DMN2400UFDQ-7	U-DFN1212-3	3,000/Tape & Reel
DMN2400UFDQ-13	U-DFN1212-3	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

U-DFN1212-3

K24 YM

K24 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: C = 2015) M = Month (ex: 9 = September)

Date Code Key

Year	2015	2016	2017	2018	8 201	9 20	020	2021	2022	2023	2024	2025
Code	С	D	Е	F	G	i	Н	ı	J	K	L	M
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Characteristic	Symbol	Value	Units		
Drain-Source Voltage			V_{DSS}	20	V
Gate-Source Voltage			V_{GSS}	±12	V
Continuous Drain Current (Note 7) V _{GS} = 4.5V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	0.9 0.7	А
Continuous Drain Current (Note 7) V _{GS} = 2.5V	I _D	0.7 0.5	А		
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	3.0	А		
Maximum Body Diode Forward Current (Note 7)	Is	0.8	A		

Thermal Characteristics (@TA = +25°C unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 6)		P_{D}	0.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ heta JA}$	283	°C/W
Total Power Dissipation (Note 7)		P _D	0.8	W
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	$R_{ heta JA}$	147	°C/W
Thermal Resistance, Junction to Case (Note 7)		$R_{\theta Jc}$	112	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

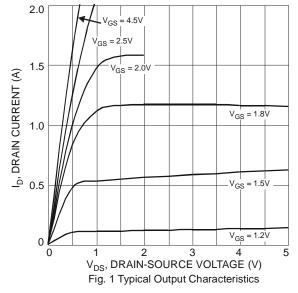
Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

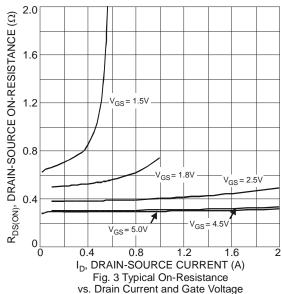
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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)	1		1			
Drain-Source Breakdown Voltage	BV _{DSS}	20	-	-	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	-		80	nA	$V_{DS} = 4.5V, V_{GS} = 0V$
Zero Gate Voltage Drain Gurrent 1j = +23 C	IDSS			100	ПА	$V_{DS} = 20V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	-	-	±1.0	μΑ	$V_{GS} = \pm 4.5 V, V_{DS} = 0 V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(th)}	0.45	-	1.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$
		-	0.35	0.6		$V_{GS} = 4.5V, I_D = 200mA$
Static Drain-Source On-Resistance	_D		0.45	0.8	Ω	$V_{GS} = 2.5V, I_D = 200mA$
Static Dialii-Source Off-Resistance	R _{DS (ON)}		0.6	1.0		$V_{GS} = 1.8V, I_D = 100mA$
		-	0.7	1.6		$V_{GS} = 1.5V, I_D = 50mA$
Forward Transfer Admittance	Y _{fs}	-	1.4	-	S	$V_{DS} = 3V, I_{D} = 200mA$
Diode Forward Voltage	V _{SD}		0.7	1.2	V	$V_{GS} = 0V, I_{S} = 500mA,$
DYNAMIC CHARACTERISTICS (Note 9)						•
Input Capacitance	C _{iss}	-	37.0	-	рF	10/1/
Output Capacitance	Coss	-	5.7	-	pF	$V_{DS} = 16V, V_{GS} = 0V,$ - f = 1.0MHz
Reverse Transfer Capacitance	Crss	-	4.2	-	pF	T = 1.0WHZ
Gate Resistance	Rg	=	68	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge	Qg	-	0.5	-	nC	V 45V V 40V
Gate-Source Charge	Qgs	=	0.07	-	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$
Gate-Drain Charge	Q _{gd}	-	0.1	-	nC	$I_D = 250 \text{mA}$
Turn-On Delay Time	t _{D(on)}	-	4.06	-	ns	10/1/
Turn-On Rise Time	tr	-	7.28	-	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time	t _{D(off)}	-	13.74	-	ns	$R_L = 47\Omega$, $R_G = 10\Omega$,
Turn-Off Fall Time	t _f	-	10.54	-	ns	$I_D = 200 \text{mA}$

Notes:

- 6. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
 7. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1-inch square copper plate.
- 8 .Short duration pulse test used to minimize self-heating effect.
- 9. Guaranteed by design. Not subject to production testing.







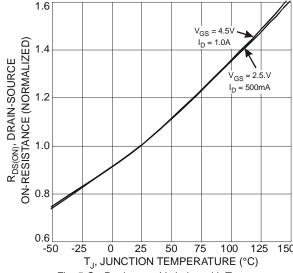
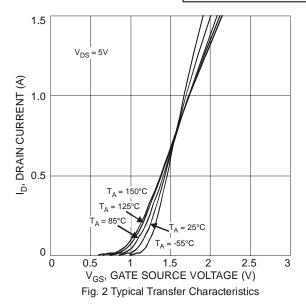


Fig. 5 On-Resistance Variation with Temperature



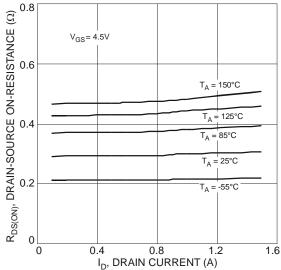


Fig. 4 Typical Drain-Source On-Resistance vs. Drain Current and Temperature

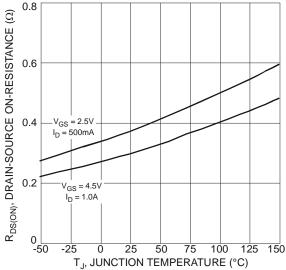


Fig. 6 On-Resistance Variation with Temperature



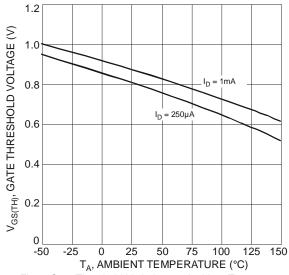
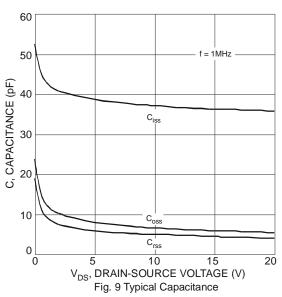
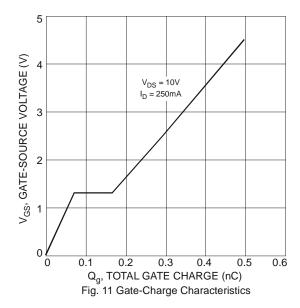
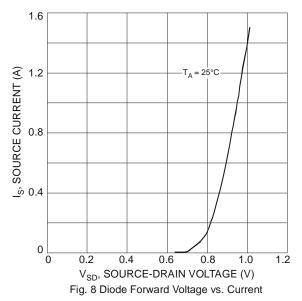
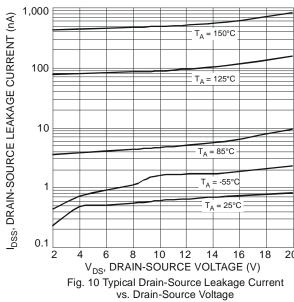


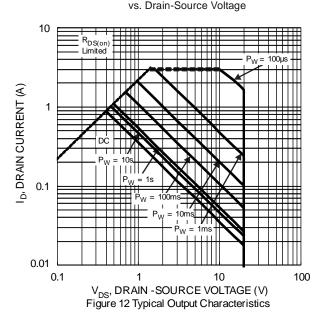
Fig. 7 Gate Threshold Variation vs. Ambient Temperature



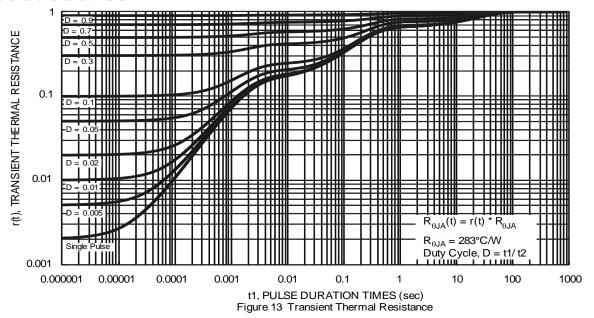






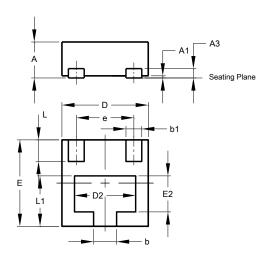






Package Outline Dimensions

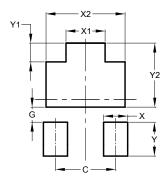
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



U-DFN1212-3									
(Type C)									
Dim	Min Max Typ								
Α	0.47	0.53	0.50						
A1	0	0.05	0.02						
А3	-	-	0.13						
b	0.27	0.37	0.32						
b1	0.17	0.27	0.22						
D	1.15	1.25	1.20						
D2	0.75	0.95	0.85						
е	-	1	0.80						
Е	1.15	1.25	1.20						
E2	0.40	0.60	0.50						
L	0.25	0.35	0.30						
L1	0.65	0.75	0.70						
All Dimensions in mm									

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



U-DFN1212-3 (Type C)					
Dimensions Value					
С	0.800				
G	0.200				
Х	0.320				
X1	0.520				
X2	1.050				
Υ	0.450				
Y1	0.250				
Y2 0.850					
All Dimensions in mm					



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